Friction in nanoelectrom echanical system s: C lamping loss in the GHz regime

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The perform ance of a wide variety of ultra-sensitive devices employing nanoelectrom echanical resonators is determined by their mechanical quality factor, yet energy dissipation in these systems remains poorly understood. Here we develop a comprehensive theory of friction in high frequency resonators caused by the radiation of elastic energy into the support substrate, referred to as clamping loss. The elastic radiation rate is found to be a strong increasing function of resonator frequency, and we argue that this mechanism will play an important role in future microwave-frequency devices.

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Nanoelectrom echanical systems (NEMS) have enormous potential for both fundam ental research and novel device applications [1, 2, 3, 4, 5]. High-frequency NEMS resonators are the leading candidates in a current e ort to observe quantum behavior in a macroscopic mechanical system [6, 7, 8]. A chieving the quantum limit requires resonator frequencies! that are signicantly higher than $k_{\rm B}\, T = h$, as well as high mechanical quality factors

$$Q$$
 !; (1)

the energy relaxation time. In this lim it the resonator's phonons will be analogous to photons in an electrom agnetic cavity, and a variety of mechanical quantum \optics" e ects have been discussed in the literature, including lasing [9], squeezing [10, 11, 12], cooling [13, 14], and quantum nondemolition measurement [15]. Macroscopic quantum tunneling of a low-tem perature beam has been predicted [16, 17], and methods to entangle NEMS with other quantum systems have been proposed [18, 19, 20], which may lead to their use in quantum com puting [21, 22, 23, 24, 25]. NEM S operating in the classical regime have already been used successfully in several novel devices, particularly for sensing and actuation. They have been used to study the Casim ir force at short distances [26, 27], and can be used as ultra-sensitive mass sensors [28, 29], recently detecting mass changes with zeptogram sensitivity [30]. They have demonstrated enorm ous potential in scanning probem icroscopy [31], including the ability to detect the spin of a single electron [32], and may also nd future applications in classical signal processing [33, 34, 35, 36, 37].

The perform ance of a mechanical resonator improves with increasing Q. However, in a series of experiments on small mechanical resonators, performed over many years by several dierent groups, the quality factor for motion in the fundamental exural and other low-lying vibrational modes has been observed to decrease approximately linearly with decreasing resonator size [38, 39, 40, 41, 42, 43, 44, 45, 46, 47, 48, 49]. This dependence is usually interpreted to be a signature of surface contamination elects, such as dissipation

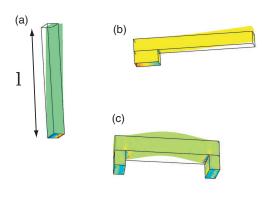


FIG. 1: (Color online) Simulated resonators. (a) $2.4\,\mathrm{GHz}$ perpendicular beam resonator. (b) $3.2\,\mathrm{GHz}$ cantilever. (c) $16\,\mathrm{GHz}$ doubly clamped beam. The material is Si and $1=50\,\mathrm{nm}$ in the examples shown. The surfaces are colored according to the z component of their traction, with yellow representing zero. The lower surfaces are attached to a semin nite elastic substrate.

caused by adsorbates or surface reconstructions. However, measurements of the temperature dependence of Q also suggest that glass-like structural two-level systems [50,51,52,53] or other internal bulk" lattice [39] or electronic [40,48] defects may also play an important role. Many energy dissipation mechanisms have been proposed to explain these experiments. However, most explanations are qualitative in nature, and a detailed quantitative analysis of the competing mechanisms has not yet been carried out.

An obvious mechanism for energy dissipation in a mechanical resonator is elastic radiation loss through the resonator supports, where the resonator is attached to a bulk substrate [54, 55, 56]. Any mechanical interaction of the resonator with its surroundings will allow vibra-

tional energy to escape to the substrate. But little is understood quantitatively about this so-called clamping loss mechanism, and some existing estimates are in contradiction with experiment. For example, the estimate [55]

$$Q_{CL} = 0.3 \frac{1}{w}^{3}$$
 (2)

for an in-plane exural mode applied to the $1\,\mathrm{G}\,\mathrm{H}\,\mathrm{z}\,\mathrm{SiC}$ beam of Huang et al. [57] results in a Q factor of about 230, smaller than observed. In the experiment of Ref. [57], the beam length is l=1:1 m and width is $w=120\,\mathrm{nm}$ [58].

In this paper we develop a general method for the accurate calculation of clamping loss rates for a wide variety of NEMS geometries. We assume at the outset that the clamping loss is small (its contribution to the total Q 1 much less than unity), allowing a perturbative treatment. If the total dissipation rate Q 1 is also 1 , as in the case of experimental interest, it will be given by a sum of contributions from each dissipation channel present. Our results suggest that clamping loss will play an important role in future GHz-frequency devices, especially above $10\,\mathrm{GHz}$.

We begin our analysis with a discussion of the fundamental mode [59] of the perpendicular beam resonator illustrated in Fig. 1a, with frequency !. The lower surface is to be attached to a sem i-in nite elastic substrate, and all exposed surfaces are stress free. ! will always be degenerate with vibrational modes of the substrate, so how can clamping loss ever be small? The answer is that an elastic wave present in the beam will be strongly re ected at the substrate when its emitted wavelength !=v, which for the fundam ental mode is of the order of l, is larger than the transverse dim ensions of the beam . Here v is a characteristic sound velocity of the substrate. The frequency-dependent transm ission probability between a sem i-in nite wire (not nite beam) and a three-dim ensional bulk solid sim ilarly vanishes in the low frequency lim it [55, 60]; however, that transm ission probability cannot be directly used to estimate clamping loss because it would only be valid for beam lengths large com pared to the wavelength (to be able to neglect the effect of cutting the wire to a nite length), and hence only to the higher frequency non-fundam entalm odes. We calculate the clamping Q by regarding the resonator's vibrational eigenfunction stress distribution (calculated with a xed lower boundary) to be a source of elastic radiation into the substrate. The radiation problem is treated

exactly within continuum elasticity theory, and the resonator vibrational modes are calculated numerically using nite-element methods. Our method applies to a wide variety of (but not necessarily all) NEMS resonator geometries, and can be used at high fundamental mode frequencies where the subdominant terms in a multipole expansion would become important.

The substrate is modeled as an isotropic elastic continuum, which is su cient for the frequencies of interest. The substrate occupies z>0, and at the surface z=0 the traction is t(x;y), which vanishes outside of the resonator contact region. The elastic displacement eld u is decomposed into longitudinal parts and transverse parts u_1 and u_t , where

$$u_1(r) = \frac{Z}{(2)^2} U_1(K) e^{iK} e^{iq_1 z}$$
 (3)

and

$$u_{t}(r) = \frac{Z}{(2)^{2}} U_{t}(K) e^{iK} r e^{iq_{t}z}$$
 (4)

Here

$$q_{1}$$
 $\frac{!^{2}}{v_{1}^{2}}$ K^{2} and q_{2} $\frac{!^{2}}{v_{+}^{2}}$ K^{2} : (5)

K $K_x e_x + K_y e_y$ is a two-dimensional wavevector. U $_1$ and U $_t$ satisfy (K + $q_1 e_z$) U $_1$ = 0 and (K + $q_2 e_z$) U = 0; and therefore can be written as U $_1$ = (K + $q_1 e_z$) (K) and U $_t$ = (K) q^1 K (K) $_{z}$ Here is a scalar eld, and $_x e_x + _y e_y$ is a vector eld.

By construction, $u_1\, and\, u_t$ satisfy the vector H elm holtz equations, conditions of longitudinality and transversality, and have only outwardly radiating components (for real q). The elastic \potentials" and are now fully determ ined by the three components of the surface traction

$$t_i = (r u)_z + 2 u_{iz};$$
 (6)

with u_{ij} the strain tensor and ; the Lamecoe cients. In terms of the Fourier transform $\,\tau(K)\,$ in the xy plane we obtain

0 1 0 1
$$t_x$$

0 $y^A = S t_y^A$; (7)

where

H ere

 $[(K^2 - q^2)^2 + 4q_1q_1K^2]$: The elastic energy current, averaged over time, is

$$j_z = \frac{!}{2} \text{ Im } (u_z r u + u r_1 u + u r_2 u);$$
 (9)

and the radiated power is

$$P \qquad \frac{Z}{d^2 r j_z} = \frac{!}{2} \quad !^2 \frac{d^2 K}{{}_{1}(2)^2} \quad {}^2 q_1 + \quad v_t^2 \frac{d^2 K}{(2)^2} \quad q_t \quad {}^2 + \frac{1}{q_t} K \quad {}^2 \quad : \tag{10}$$

TABLE I: Resonator frequency !=2 and Q factor as a function of size 1. Beam s have a 5 nm thickness and 10 nm w idth.

	20 nm	50 nm	100 nm
perpendicular	14:7 G H z	2:42 G H z	607M Hz
beam	$Q = 4:1 10^3$	$Q = 2.5 10^5$	$Q = 7:1 10^6$
cantilever	30:1 G H z	320GHz	695M Hz
beam	$Q = 1:0 10^3$	$Q = 4:1 10^5$	$Q = 1:4 10^7$
doubly clamped	97:1 G H z	16:0GHz	3:85GHz
beam	Q = 21	$Q = 2:1 10^3$	$Q = 7:9 10^4$

The integration domains $_1$ and $_t$ in (10) have K jless than $!=v_1$ and $!=v_t$; respectively. Given the surface traction t(x;y), P is now readily evaluated. The damping time is E=P; with E the initial energy of the resonator. The required traction information can be accurately determined by numerical nite-element methods, without the need to include a large \environment" in the simulation. Our numerical results converge to the precision reported here after a few tens of thousands of volume elements.

Our results are summarized in Table I. The Q factor for a perpendicular beam resonator shows that clamping loss in that case is probably negligible below $1\,\mathrm{G}\,\mathrm{H}\,\mathrm{z}$, but that it becomes quite signicant above $10\,\mathrm{G}\,\mathrm{H}\,\mathrm{z}$. An approximate analytic expression for Q in this geometry can be obtained by constructing the fundamental-mode eigenfunction with thin-beam theory, and keeping only the leading (monopole) transverse stressmoment in (10). This leads to [58]

$$Q = \frac{w}{t} + \frac{1}{4} + \frac{5}{2}$$
; (11)

where is a material-dependent parameter, equal to 0.194 for Si, and where

$$v_1 A^{1=2}$$
; with A tw: (12)

TABLE II: A sym ptotic Q factor (11) for the perpendicular beam resonator. D in ensions are the same as in Table I. The frequency is calculated analytically using thin-beam theory, and =2 is $599\,\mathrm{G}\,\mathrm{Hz}$. Q $_{\mathrm{PJ}}$ is taken from Ref. [56].

perpendicular beam	20 nm	50 nm	100 nm
frequency	17:1GHz	2:73GHz	683M H z
asym ptotic Q	2 : 5 10 ³	$2:2 10^5$	7 : 1 10 ⁶
QpJ	1:7 10 ³	1 : 6 10 ⁵	52 10 ⁶

is a characteristic frequency above which the resonator beam \mid with cross-sectional area A \mid can support nonuniform transverse modes, changing the dynamics from one dimensional to three dimensional. The validity of the result (11) relies on the applicability of thin-beam theory; it is therefore asymptotically exact in the ! limit. The beam theory frequency and asymptotic Q factor for the perpendicular resonator is given in Table II, showing that the expression (11) becomes unreliable (overestimating dissipation) above about 10 GHz; which is the regime where clamping loss just begins to be important. Also given in Table II is a simpler (but not asymptotically exact) estimate by Photiadis and Judge [56],

$$Q_{PJ} = 32 \frac{1^5}{wt^4};$$
 (13)

which predicts clamping loss rates somewhat higher than that given by (11).

The Q factor for the cantilever and doubly clamped beam resonators behave quite similarly to the perpendicular resonator, when viewed as a function of frequency instead of size. In all cases the Q factors at a few GHz are about 10^5 , but fall to around 10^3 in the few tens of GHz regime. Loss at $100\,\mathrm{GHz}$ is severe. It is reasonable to assume that this trend is quite general, and will apply to other resonator geometries as well. The development of ultrahigh-Q NEMS resonators above about $10\,\mathrm{GHz}$ will require phononic bandgap engineering [61] or other methods of acoustic isolation.

Finally, we brie y comment on the high frequency behavior of the asymptotic expression (11), which we have argued to be exact (for the perpendicular beam resonator) in the low-frequency limit. It follows from our earlier discussion that Q would be expected to be of order unity at the frequency: Thus, it is tempting to conclude that the formula (11) can be used for all frequencies in the range 0 $^<$! $^<$, which would be incorrect, despite the fact that it is accurate at the two endpoints.

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